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### Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### **Details**

Product Status	Active
Number of LABs/CLBs	3411
Number of Logic Elements/Cells	43661
Total RAM Bits	2138112
Number of I/O	218
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	324-LFBGA, CSPBGA
Supplier Device Package	324-CSPBGA (15x15)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/xilinx/xc6slx45-2csg324i">https://www.e-xfl.com/product-detail/xilinx/xc6slx45-2csg324i</a>

Table 10: Differential I/O Standard DC Input and Output Levels

I/O Standard	V <sub>ID</sub>		V <sub>ICM</sub>		V <sub>OD</sub>		V <sub>OCM</sub>		V <sub>OH</sub>	V <sub>OL</sub>
	mV, Min	mV, Max	V, Min	V, Max	mV, Min	mV, Max	V, Min	V, Max	V, Min	V, Max
LVDS_33 <sup>(2)(3)</sup>	100	600	0.3	2.35	247	454	1.125	1.375	—	—
LVDS_25 <sup>(2)(3)</sup>	100	600	0.3	2.35	247	454	1.125	1.375	—	—
BLVDS_25 <sup>(2)(3)</sup>	100	—	0.3	2.35	240	460	Typical 50% V <sub>CCO</sub>		—	—
MINI_LVDS_33	200	600	0.3	1.95	300	600	1.0	1.4	—	—
MINI_LVDS_25	200	600	0.3	1.95	300	600	1.0	1.4	—	—
LVPECL_33 <sup>(2)(3)</sup>	100	1000	0.3	2.8 <sup>(1)</sup>	Inputs only					
LVPECL_25 <sup>(2)(3)</sup>	100	1000	0.3	1.95	Inputs only					
RSDS_33 <sup>(2)(3)</sup>	100	—	0.3	1.5	100	400	1.0	1.4	—	—
RSDS_25 <sup>(2)(3)</sup>	100	—	0.3	1.5	100	400	1.0	1.4	—	—
TMDS_33	150	1200	2.7	3.23 <sup>(1)</sup>	400	800	V <sub>CCO</sub> – 0.405	V <sub>CCO</sub> – 0.190	—	—
PPDS_33 <sup>(2)(3)</sup>	100	400	0.2	2.3	100	400	0.5	1.4	—	—
PPDS_25 <sup>(2)(3)</sup>	100	400	0.2	2.3	100	400	0.5	1.4	—	—
DISPLAY_PORT	190	1260	0.3	2.35	—	—	Typical 50% V <sub>CCO</sub>		—	—
DIFF_MOBILE_DDR	100	—	0.78	1.02	—	—	—	—	90% V <sub>CCO</sub>	10% V <sub>CCO</sub>
DIFF_HSTL_I	100	—	0.68	0.9	—	—	—	—	V <sub>CCO</sub> – 0.4	0.4
DIFF_HSTL_II	100	—	0.68	0.9	—	—	—	—	V <sub>CCO</sub> – 0.4	0.4
DIFF_HSTL_III	100	—	0.68	0.9	—	—	—	—	V <sub>CCO</sub> – 0.4	0.4
DIFF_HSTL_I_18	100	—	0.8	1.1	—	—	—	—	V <sub>CCO</sub> – 0.4	0.4
DIFF_HSTL_II_18	100	—	0.8	1.1	—	—	—	—	V <sub>CCO</sub> – 0.4	0.4
DIFF_HSTL_III_18	100	—	0.8	1.1	—	—	—	—	V <sub>CCO</sub> – 0.4	0.4
DIFF_SSTL3_I	100	—	1.0	1.9	—	—	—	—	V <sub>TT</sub> + 0.6	V <sub>TT</sub> – 0.6
DIFF_SSTL3_II	100	—	1.0	1.9	—	—	—	—	V <sub>TT</sub> + 0.8	V <sub>TT</sub> – 0.8
DIFF_SSTL2_I	100	—	1.0	1.5	—	—	—	—	V <sub>TT</sub> + 0.61	V <sub>TT</sub> – 0.61
DIFF_SSTL2_II	100	—	1.0	1.5	—	—	—	—	V <sub>TT</sub> + 0.81	V <sub>TT</sub> – 0.81
DIFF_SSTL18_I	100	—	0.7	1.1	—	—	—	—	V <sub>TT</sub> + 0.47	V <sub>TT</sub> – 0.47
DIFF_SSTL18_II	100	—	0.7	1.1	—	—	—	—	V <sub>TT</sub> + 0.6	V <sub>TT</sub> – 0.6
DIFF_SSTL15_II	100	—	0.55	0.95	—	—	—	—	V <sub>TT</sub> + 0.4	V <sub>TT</sub> – 0.4

**Notes:**

1. LVPECL\_33 and TMDS\_33 maximum V<sub>ICM</sub> is the lower of V (maximum) or V<sub>CCAUX</sub> – (V<sub>ID</sub>/2)
2. When V<sub>CCAUX</sub> = 3.3V, the DCD can be higher than 5% for V<sub>ICM</sub> < 0.7V when using these I/O standards: LVDS\_25, LVDS\_33, BLVDS\_25, LVPECL\_25, LVPECL\_33, RSDS\_25, RSDS\_33, PPDS\_25, and PPDS\_33.
3. The -1L devices require V<sub>CCAUX</sub> = 2.5V when using the LVDS\_25, LVDS\_33, BLVDS\_25, LVPECL\_25, RSDS\_25, RSDS\_33, PPDS\_25, and PPDS\_33 I/O standards on inputs. LVPECL\_33 is not supported in the -1L devices.

Table 14: GTP Transceiver Current Supply (per Lane)

Symbol	Description	Typ <sup>(1)</sup>	Max	Units
$I_{MGTAVCC}$	GTP transceiver internal analog supply current	40.4	Note 2	mA
$I_{MGTAVTTX}$	GTP transmitter termination supply current	27.4		mA
$I_{MGTAVTRX}$	GTP receiver termination supply current	13.6		mA
$I_{MGTAVCCPLL}$	GTP transmitter and receiver PLL supply current	28.7		mA
$R_{MGTRREF}$	Precision reference resistor for internal calibration termination	$50.0 \pm 1\%$ tolerance		$\Omega$

**Notes:**

1. Typical values are specified at nominal voltage, 25°C, with a 2.5 Gb/s line rate, with a shared PLL use mode.
2. Values for currents of other transceiver configurations and conditions can be obtained by using the XPOWER Estimator (XPE) or XPOWER Analyzer (XPA) tools.

Table 15: GTP Transceiver Quiescent Supply Current (per Lane)<sup>(1)(2)(3)(4)</sup>

Symbol	Description	Typ <sup>(5)</sup>	Max	Units
$I_{MGTAVCCQ}$	Quiescent MGTAVCC supply current	1.7	Note 2	mA
$I_{MGTAVTTXQ}$	Quiescent MGTAVTTX supply current	0.1		mA
$I_{MGTAVTRXQ}$	Quiescent MGTAVTRX supply current	1.2		mA
$I_{MGTAVCCPLQ}$	Quiescent MGTAVCCPLL supply current	1.0		mA

**Notes:**

1. Device powered and unconfigured.
2. Currents for conditions other than values specified in this table can be obtained by using the XPOWER Estimator (XPE) or XPOWER Analyzer (XPA) tools.
3. GTP transceiver quiescent supply current for an entire device can be calculated by multiplying the values in this table by the number of available GTP transceivers.
4. Does not include power-up MGTAVTTRCAL supply current during device configuration.
5. Typical values are specified at nominal voltage, 25°C.

## Performance Characteristics

This section provides the performance characteristics of some common functions and designs implemented in Spartan-6 devices. The numbers reported here are worst-case values; they have all been fully characterized. These values are subject to the same guidelines as the [Switching Characteristics, page 19](#).

**Table 25: Interface Performances**

<b>Description</b>	<b>I/O Resource</b>	<b>Clock Buffer</b>	<b>Data Width</b>	<b>Speed Grade</b>				<b>Units</b>		
				<b>-3</b>	<b>-3N</b>	<b>-2</b>	<b>-1L</b>			
<b>Networking Applications<sup>(1)</sup></b>										
SDR LVDS transmitter or receiver	IOB SDR register	BUFG	—	400	400	375	250	Mb/s		
DDR LVDS transmitter or receiver	ODDR2/IDDR2 register	2 BUFGs	—	800	800	750	500	Mb/s		
SDR LVDS transmitter	OSERDES2	BUFPLL	2	500	500	500	250	Mb/s		
			3	750	750	750	375	Mb/s		
			4-8	1080	1050	950	500	Mb/s		
DDR LVDS transmitter	OSERDES2	2 BUFIO2s	2	500	500	500	250	Mb/s		
			3	750	750	750	375	Mb/s		
			4-8	1080	1050	950	500	Mb/s		
SDR LVDS receiver	ISERDES2 in RETIMED mode	BUFPLL	2	500	500	500	—	Mb/s		
			3	750	750	750	—	Mb/s		
			4-8	1080	1050	950	—	Mb/s		
DDR LVDS receiver	ISERDES2 in RETIMED mode	2 BUFIO2s	2	500	500	500	—	Mb/s		
			3	750	750	750	—	Mb/s		
			4-8	1080	1050	950	—	Mb/s		
<b>Memory Interfaces (Implemented using the Spartan-6 FPGA Memory Controller Block)<sup>(2)</sup></b>										
<b>Standard Performance (Standard V<sub>CCINT</sub>)</b>										
DDR				400	<a href="#">Note 4</a>	400	350	Mb/s		
DDR2				667	<a href="#">Note 4</a>	625	400	Mb/s		
DDR3				800	<a href="#">Note 4</a>	667	—	Mb/s		
LPDDR (Mobile_DDR)				400	<a href="#">Note 4</a>	400	350	Mb/s		
<b>Extended Performance (Requires Extended Performance V<sub>CCINT</sub>)<sup>(3)</sup></b>										
DDR2				800	<a href="#">Note 4</a>	667	—	Mb/s		

**Notes:**

- Refer to [XAPP1064](#), *Source-Synchronous Serialization and Deserialization (up to 1050 Mb/s)* and [UG381](#), *Spartan-6 FPGA SelectIO Resources User Guide*.
- Refer to [UG388](#), *Spartan-6 FPGA Memory Controller User Guide*.
- Extended Memory Controller block performance for DDR2 can be achieved using the extended performance V<sub>CCINT</sub> range from [Table 2](#).
- The LX4 device, all devices in the TQG144 and CPG196 packages, and the -3N speed grade do not support a Memory Controller Block.

## Switching Characteristics

All values represented in this data sheet are based on these speed specifications: v1.20 for -3, -3N, and -2; and v1.08 for -1L. Switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

### Advance

These specifications are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

### Preliminary

These specifications are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

### Production

These specifications are released once enough production silicon of a particular device family member has been characterized to provide full correlation between specifications and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are always representative of worst-case supply voltage and junction temperature conditions.

Since individual family members are produced at different times, the migration from one category to another depends completely on the status of the fabrication process for each device.

The -1L speed grade refers to the lower-power Spartan-6 devices. The -3N speed grade refers to the Spartan-6 devices that do not support MCB functionality.

**Table 26** correlates the current status of each Spartan-6 device on a per speed grade basis.

## Testing of Switching Characteristics

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values.

For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer and back-annotate to the simulation net list. Unless otherwise noted, values apply to all Spartan-6 devices.

**Table 26: Spartan-6 Device Speed Grade Designations**

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XC6SLX4 <sup>(1)</sup>			-3, -2, -1L
XC6SLX9			-3, -3N, -2, -1L
XC6SLX16			-3, -3N, -2, -1L
XC6SLX25			-3, -3N, -2, -1L
XC6SLX25T			-3, -3N, -2
XC6SLX45			-3, -3N, -2, -1L
XC6SLX45T			-3, -3N, -2
XC6SLX75			-3, -3N, -2, -1L
XC6SLX75T			-3, -3N, -2
XC6SLX100			-3, -3N, -2, -1L
XC6SLX100T			-3, -3N, -2
XC6SLX150			-3, -3N, -2, -1L
XC6SLX150T			-3, -3N, -2
XA6SLX4			-3, -2
XA6SLX9			-3, -2
XA6SLX16			-3, -2
XA6SLX25			-3, -2
XA6SLX25T			-3, -2
XA6SLX45			-3, -2
XA6SLX45T			-3, -2
XA6SLX75			-3, -2
XA6SLX75T			-3, -2
XA6SLX100			-2
XQ6SLX75			-2, -1L
XQ6SLX75T			-3, -2
XQ6SLX150			-2, -1L
XQ6SLX150T			-3, -2

### Notes:

1. The XC6SLX4 is not available in the -3N speed grade.

## Production Silicon and ISE Software Status

In some cases, a particular family member (and speed grade) is released to production before a speed specification is released with the correct label (Advance, Preliminary, Production). Any labeling discrepancies are corrected in subsequent speed specification releases. [Table 27](#) lists the production released Spartan-6 family member, speed grade, and the minimum corresponding supported speed specification version and ISE® software revisions. The ISE software and speed specifications listed are the minimum releases required for production. All subsequent releases of software and speed specifications are valid.

**Table 27: Spartan-6 Device Production Software and Speed Specification Release<sup>(1)</sup>**

Device	Speed Grade Designations <sup>(2)</sup>			
	-3 <sup>(3)</sup>	-3N	-2 <sup>(4)</sup>	-1L
XC6SLX4	ISE 12.4 v1.15	N/A	ISE 12.3 v1.12 <sup>(5)</sup>	ISE 13.2 v1.07
XC6SLX9	ISE 12.4 v1.15	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.3 v1.12 <sup>(5)</sup>	ISE 13.2 v1.07
XC6SLX16	ISE 12.1 v1.08	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 11.5 v1.06	ISE 13.2 v1.07
XC6SLX25	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.2 v1.07
XC6SLX25T	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	N/A
XC6SLX45	ISE 12.1 v1.08	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 11.5 v1.07	ISE 13.1 v1.06
XC6SLX45T	ISE 12.1 v1.08	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.1 v1.08	N/A
XC6SLX75	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.2 v1.07
XC6SLX75T	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	N/A
XC6SLX100	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 v1.06
XC6SLX100T	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	N/A
XC6SLX150	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 v1.06
XC6SLX150T	ISE 12.2 v1.11 <sup>(6)</sup>	ISE 13.1 Update v1.18 <sup>(7)</sup>	ISE 12.2 v1.11 <sup>(6)</sup>	N/A
XA6SLX4	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX9	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX16	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX25	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX25T	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX45	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX45T	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX75	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX75T	ISE 13.2 v1.19	N/A	ISE 13.2 v1.19	N/A
XA6SLX100	N/A	N/A	ISE 13.3 v1.20	N/A

Table 28: IOB Switching Characteristics for the Commercial (XC) Spartan-6 Devices (Cont'd)

I/O Standard	T <sub>IOPI</sub>				T <sub>LOOP</sub>				T <sub>IOTP</sub>				Units	
	Speed Grade				Speed Grade				Speed Grade					
	-3	-3N	-2	-1L <sup>(1)</sup>	-3	-3N	-2	-1L <sup>(1)</sup>	-3	-3N	-2	-1L <sup>(1)</sup>		
LVCMOS15, Slow, 8 mA	0.98	1.10	1.23	1.79	2.30	2.44	2.64	3.25	2.30	2.44	2.64	3.25	ns	
LVCMOS15, Slow, 12 mA	0.98	1.10	1.23	1.79	2.03	2.17	2.37	2.99	2.03	2.17	2.37	2.99	ns	
LVCMOS15, Slow, 16 mA	0.98	1.10	1.23	1.79	2.01	2.15	2.35	2.97	2.01	2.15	2.35	2.97	ns	
LVCMOS15, Fast, 2 mA	0.98	1.10	1.23	1.79	3.29	3.43	3.63	4.24	3.29	3.43	3.63	4.24	ns	
LVCMOS15, Fast, 4 mA	0.98	1.10	1.23	1.79	2.27	2.41	2.61	3.22	2.27	2.41	2.61	3.22	ns	
LVCMOS15, Fast, 6 mA	0.98	1.10	1.23	1.79	1.78	1.92	2.12	2.74	1.78	1.92	2.12	2.74	ns	
LVCMOS15, Fast, 8 mA	0.98	1.10	1.23	1.79	1.73	1.87	2.07	2.69	1.73	1.87	2.07	2.69	ns	
LVCMOS15, Fast, 12 mA	0.98	1.10	1.23	1.79	1.73	1.87	2.07	2.64	1.73	1.87	2.07	2.64	ns	
LVCMOS15, Fast, 16 mA	0.98	1.10	1.23	1.79	1.73	1.87	2.07	2.64	1.73	1.87	2.07	2.64	ns	
LVCMOS15_JEDEC, QUIETIO, 2 mA	1.03	1.15	1.28	1.49	5.49	5.63	5.83	6.37	5.49	5.63	5.83	6.37	ns	
LVCMOS15_JEDEC, QUIETIO, 4 mA	1.03	1.15	1.28	1.49	4.61	4.75	4.95	5.51	4.61	4.75	4.95	5.51	ns	
LVCMOS15_JEDEC, QUIETIO, 6 mA	1.03	1.15	1.28	1.49	4.07	4.21	4.41	4.97	4.07	4.21	4.41	4.97	ns	
LVCMOS15_JEDEC, QUIETIO, 8 mA	1.03	1.15	1.28	1.49	3.92	4.06	4.26	4.81	3.92	4.06	4.26	4.81	ns	
LVCMOS15_JEDEC, QUIETIO, 12 mA	1.03	1.15	1.28	1.49	3.54	3.68	3.88	4.51	3.54	3.68	3.88	4.51	ns	
LVCMOS15_JEDEC, QUIETIO, 16 mA	1.03	1.15	1.28	1.49	3.33	3.47	3.67	4.31	3.33	3.47	3.67	4.31	ns	
LVCMOS15_JEDEC, Slow, 2 mA	1.03	1.15	1.28	1.49	4.18	4.32	4.52	5.13	4.18	4.32	4.52	5.13	ns	
LVCMOS15_JEDEC, Slow, 4 mA	1.03	1.15	1.28	1.49	3.42	3.56	3.76	4.35	3.42	3.56	3.76	4.35	ns	
LVCMOS15_JEDEC, Slow, 6 mA	1.03	1.15	1.28	1.49	2.29	2.43	2.63	3.25	2.29	2.43	2.63	3.25	ns	
LVCMOS15_JEDEC, Slow, 8 mA	1.03	1.15	1.28	1.49	2.30	2.44	2.64	3.26	2.30	2.44	2.64	3.26	ns	
LVCMOS15_JEDEC, Slow, 12 mA	1.03	1.15	1.28	1.49	2.01	2.15	2.35	2.97	2.01	2.15	2.35	2.97	ns	
LVCMOS15_JEDEC, Slow, 16 mA	1.03	1.15	1.28	1.49	2.01	2.15	2.35	2.97	2.01	2.15	2.35	2.97	ns	
LVCMOS15_JEDEC, Fast, 2 mA	1.03	1.15	1.28	1.49	3.28	3.42	3.62	4.22	3.28	3.42	3.62	4.22	ns	
LVCMOS15_JEDEC, Fast, 4 mA	1.03	1.15	1.28	1.49	2.27	2.41	2.61	3.23	2.27	2.41	2.61	3.23	ns	
LVCMOS15_JEDEC, Fast, 6 mA	1.03	1.15	1.28	1.49	1.78	1.92	2.12	2.74	1.78	1.92	2.12	2.74	ns	
LVCMOS15_JEDEC, Fast, 8 mA	1.03	1.15	1.28	1.49	1.73	1.87	2.07	2.69	1.73	1.87	2.07	2.69	ns	
LVCMOS15_JEDEC, Fast, 12 mA	1.03	1.15	1.28	1.49	1.73	1.87	2.07	2.63	1.73	1.87	2.07	2.63	ns	
LVCMOS15_JEDEC, Fast, 16 mA	1.03	1.15	1.28	1.49	1.73	1.87	2.07	2.63	1.73	1.87	2.07	2.63	ns	
LVCMOS12, QUIETIO, 2 mA	0.91	1.03	1.16	1.51	6.40	6.54	6.74	7.30	6.40	6.54	6.74	7.30	ns	
LVCMOS12, QUIETIO, 4 mA	0.91	1.03	1.16	1.51	4.98	5.12	5.32	5.90	4.98	5.12	5.32	5.90	ns	
LVCMOS12, QUIETIO, 6 mA	0.91	1.03	1.16	1.51	4.65	4.79	4.99	5.55	4.65	4.79	4.99	5.55	ns	
LVCMOS12, QUIETIO, 8 mA	0.91	1.03	1.16	1.51	4.23	4.37	4.57	5.21	4.23	4.37	4.57	5.21	ns	
LVCMOS12, QUIETIO, 12 mA	0.91	1.03	1.16	1.51	3.98	4.12	4.32	4.94	3.98	4.12	4.32	4.94	ns	
LVCMOS12, Slow, 2 mA	0.91	1.03	1.16	1.51	4.98	5.12	5.32	5.91	4.98	5.12	5.32	5.91	ns	
LVCMOS12, Slow, 4 mA	0.91	1.03	1.16	1.51	2.84	2.98	3.18	3.81	2.84	2.98	3.18	3.81	ns	
LVCMOS12, Slow, 6 mA	0.91	1.03	1.16	1.51	2.77	2.91	3.11	3.72	2.77	2.91	3.11	3.72	ns	
LVCMOS12, Slow, 8 mA	0.91	1.03	1.16	1.51	2.34	2.48	2.68	3.31	2.34	2.48	2.68	3.31	ns	
LVCMOS12, Slow, 12 mA	0.91	1.03	1.16	1.51	2.08	2.22	2.42	3.06	2.08	2.22	2.42	3.06	ns	

Table 29: IOB Switching Characteristics for the Automotive XA Spartan-6 and the Spartan-6Q Devices<sup>(1)</sup> (Cont'd)

I/O Standard	T <sub>IOP1</sub>		T <sub>IOOP</sub>		T <sub>IOTP</sub>		Units	
	Speed Grade		Speed Grade		Speed Grade			
	-3	-2	-3	-2	-3	-2		
LVCMOS18, QUIETIO, 16 mA	1.25	1.43	3.34	3.54	3.34	3.54	ns	
LVCMOS18, QUIETIO, 24 mA	1.25	1.43	3.18	3.38	3.18	3.38	ns	
LVCMOS18, Slow, 2 mA	1.25	1.43	4.79	4.99	4.79	4.99	ns	
LVCMOS18, Slow, 4 mA	1.25	1.43	3.84	4.04	3.84	4.04	ns	
LVCMOS18, Slow, 6 mA	1.25	1.43	3.17	3.37	3.17	3.37	ns	
LVCMOS18, Slow, 8 mA	1.25	1.43	2.37	2.57	2.37	2.57	ns	
LVCMOS18, Slow, 12 mA	1.25	1.43	2.13	2.33	2.13	2.33	ns	
LVCMOS18, Slow, 16 mA	1.25	1.43	2.13	2.33	2.13	2.33	ns	
LVCMOS18, Slow, 24 mA	1.25	1.43	2.13	2.33	2.13	2.33	ns	
LVCMOS18, Fast, 2 mA	1.25	1.43	3.78	3.98	3.78	3.98	ns	
LVCMOS18, Fast, 4 mA	1.25	1.43	2.54	2.74	2.54	2.74	ns	
LVCMOS18, Fast, 6 mA	1.25	1.43	2.02	2.22	2.02	2.22	ns	
LVCMOS18, Fast, 8 mA	1.25	1.43	1.95	2.15	1.95	2.15	ns	
LVCMOS18, Fast, 12 mA	1.25	1.43	1.85	2.05	1.85	2.05	ns	
LVCMOS18, Fast, 16 mA	1.25	1.43	1.85	2.05	1.85	2.05	ns	
LVCMOS18, Fast, 24 mA	1.25	1.43	1.85	2.05	1.85	2.05	ns	
LVCMOS18_JEDEC, QUIETIO, 2 mA	1.01	1.19	6.09	6.29	6.09	6.29	ns	
LVCMOS18_JEDEC, QUIETIO, 4 mA	1.01	1.19	4.89	5.09	4.89	5.09	ns	
LVCMOS18_JEDEC, QUIETIO, 6 mA	1.01	1.19	4.20	4.40	4.20	4.40	ns	
LVCMOS18_JEDEC, QUIETIO, 8 mA	1.01	1.19	3.87	4.07	3.87	4.07	ns	
LVCMOS18_JEDEC, QUIETIO, 12 mA	1.01	1.19	3.49	3.69	3.49	3.69	ns	
LVCMOS18_JEDEC, QUIETIO, 16 mA	1.01	1.19	3.34	3.54	3.34	3.54	ns	
LVCMOS18_JEDEC, QUIETIO, 24 mA	1.01	1.19	3.17	3.37	3.17	3.37	ns	
LVCMOS18_JEDEC, Slow, 2 mA	1.01	1.19	4.79	4.99	4.79	4.99	ns	
LVCMOS18_JEDEC, Slow, 4 mA	1.01	1.19	3.84	4.04	3.84	4.04	ns	
LVCMOS18_JEDEC, Slow, 6 mA	1.01	1.19	3.18	3.38	3.18	3.38	ns	
LVCMOS18_JEDEC, Slow, 8 mA	1.01	1.19	2.37	2.57	2.37	2.57	ns	
LVCMOS18_JEDEC, Slow, 12 mA	1.01	1.19	2.13	2.33	2.13	2.33	ns	
LVCMOS18_JEDEC, Slow, 16 mA	1.01	1.19	2.13	2.33	2.13	2.33	ns	
LVCMOS18_JEDEC, Slow, 24 mA	1.01	1.19	2.13	2.33	2.13	2.33	ns	
LVCMOS18_JEDEC, Fast, 2 mA	1.01	1.19	3.75	3.95	3.75	3.95	ns	
LVCMOS18_JEDEC, Fast, 4 mA	1.01	1.19	2.54	2.74	2.54	2.74	ns	
LVCMOS18_JEDEC, Fast, 6 mA	1.01	1.19	2.02	2.22	2.02	2.22	ns	
LVCMOS18_JEDEC, Fast, 8 mA	1.01	1.19	1.94	2.14	1.94	2.14	ns	
LVCMOS18_JEDEC, Fast, 12 mA	1.01	1.19	1.86	2.06	1.86	2.06	ns	
LVCMOS18_JEDEC, Fast, 16 mA	1.01	1.19	1.86	2.06	1.86	2.06	ns	
LVCMOS18_JEDEC, Fast, 24 mA	1.01	1.19	1.86	2.06	1.86	2.06	ns	

Table 29: IOB Switching Characteristics for the Automotive XA Spartan-6 and the Spartan-6Q Devices<sup>(1)</sup> (Cont'd)

I/O Standard	T <sub>IOP1</sub>		T <sub>IOP0</sub>		T <sub>IOTP</sub>		Units	
	Speed Grade		Speed Grade		Speed Grade			
	-3	-2	-3	-2	-3	-2		
LVCMOS15, QUIETIO, 2 mA	1.05	1.23	5.63	5.83	5.63	5.83	ns	
LVCMOS15, QUIETIO, 4 mA	1.05	1.23	4.75	4.95	4.75	4.95	ns	
LVCMOS15, QUIETIO, 6 mA	1.05	1.23	4.21	4.41	4.21	4.41	ns	
LVCMOS15, QUIETIO, 8 mA	1.05	1.23	4.05	4.25	4.05	4.25	ns	
LVCMOS15, QUIETIO, 12 mA	1.05	1.23	3.74	3.94	3.74	3.94	ns	
LVCMOS15, QUIETIO, 16 mA	1.05	1.23	3.52	3.72	3.52	3.72	ns	
LVCMOS15, Slow, 2 mA	1.05	1.23	4.32	4.52	4.32	4.52	ns	
LVCMOS15, Slow, 4 mA	1.05	1.23	3.58	3.78	3.58	3.78	ns	
LVCMOS15, Slow, 6 mA	1.05	1.23	2.45	2.65	2.45	2.65	ns	
LVCMOS15, Slow, 8 mA	1.05	1.23	2.46	2.66	2.46	2.66	ns	
LVCMOS15, Slow, 12 mA	1.05	1.23	2.17	2.37	2.17	2.37	ns	
LVCMOS15, Slow, 16 mA	1.05	1.23	2.15	2.35	2.15	2.35	ns	
LVCMOS15, Fast, 2 mA	1.05	1.23	3.43	3.63	3.43	3.63	ns	
LVCMOS15, Fast, 4 mA	1.05	1.23	2.42	2.62	2.42	2.62	ns	
LVCMOS15, Fast, 6 mA	1.05	1.23	1.92	2.12	1.92	2.12	ns	
LVCMOS15, Fast, 8 mA	1.05	1.23	1.87	2.07	1.87	2.07	ns	
LVCMOS15, Fast, 12 mA	1.05	1.23	1.87	2.07	1.87	2.07	ns	
LVCMOS15, Fast, 16 mA	1.05	1.23	1.87	2.07	1.87	2.07	ns	
LVCMOS15_JEDEC, QUIETIO, 2 mA	1.10	1.28	5.64	5.84	5.64	5.84	ns	
LVCMOS15_JEDEC, QUIETIO, 4 mA	1.10	1.28	4.75	4.95	4.75	4.95	ns	
LVCMOS15_JEDEC, QUIETIO, 6 mA	1.10	1.28	4.21	4.41	4.21	4.41	ns	
LVCMOS15_JEDEC, QUIETIO, 8 mA	1.10	1.28	4.06	4.26	4.06	4.26	ns	
LVCMOS15_JEDEC, QUIETIO, 12 mA	1.10	1.28	3.75	3.95	3.75	3.95	ns	
LVCMOS15_JEDEC, QUIETIO, 16 mA	1.10	1.28	3.53	3.73	3.53	3.73	ns	
LVCMOS15_JEDEC, Slow, 2 mA	1.10	1.28	4.32	4.52	4.32	4.52	ns	
LVCMOS15_JEDEC, Slow, 4 mA	1.10	1.28	3.56	3.76	3.56	3.76	ns	
LVCMOS15_JEDEC, Slow, 6 mA	1.10	1.28	2.44	2.64	2.44	2.64	ns	
LVCMOS15_JEDEC, Slow, 8 mA	1.10	1.28	2.47	2.67	2.47	2.67	ns	
LVCMOS15_JEDEC, Slow, 12 mA	1.10	1.28	2.15	2.35	2.15	2.35	ns	
LVCMOS15_JEDEC, Slow, 16 mA	1.10	1.28	2.15	2.35	2.15	2.35	ns	
LVCMOS15_JEDEC, Fast, 2 mA	1.10	1.28	3.43	3.63	3.43	3.63	ns	
LVCMOS15_JEDEC, Fast, 4 mA	1.10	1.28	2.42	2.62	2.42	2.62	ns	
LVCMOS15_JEDEC, Fast, 6 mA	1.10	1.28	1.92	2.12	1.92	2.12	ns	
LVCMOS15_JEDEC, Fast, 8 mA	1.10	1.28	1.87	2.07	1.87	2.07	ns	
LVCMOS15_JEDEC, Fast, 12 mA	1.10	1.28	1.87	2.07	1.87	2.07	ns	
LVCMOS15_JEDEC, Fast, 16 mA	1.10	1.28	1.87	2.07	1.87	2.07	ns	
LVCMOS12, QUIETIO, 2 mA	0.98	1.16	6.54	6.74	6.54	6.74	ns	
LVCMOS12, QUIETIO, 4 mA	0.98	1.16	5.12	5.32	5.12	5.32	ns	

Table 29: IOB Switching Characteristics for the Automotive XA Spartan-6 and the Spartan-6Q Devices<sup>(1)</sup> (Cont'd)

I/O Standard	$T_{IOPI}$		$T_{IOOP}$		$T_{IOTP}$		Units	
	Speed Grade		Speed Grade		Speed Grade			
	-3	-2	-3	-2	-3	-2		
LVCMOS12, QUIETIO, 6 mA	0.98	1.16	4.79	4.99	4.79	4.99	ns	
LVCMOS12, QUIETIO, 8 mA	0.98	1.16	4.43	4.63	4.43	4.63	ns	
LVCMOS12, QUIETIO, 12 mA	0.98	1.16	4.18	4.38	4.18	4.38	ns	
LVCMOS12, Slow, 2 mA	0.98	1.16	5.12	5.32	5.12	5.32	ns	
LVCMOS12, Slow, 4 mA	0.98	1.16	3.00	3.20	3.00	3.20	ns	
LVCMOS12, Slow, 6 mA	0.98	1.16	2.91	3.11	2.91	3.11	ns	
LVCMOS12, Slow, 8 mA	0.98	1.16	2.51	2.71	2.51	2.71	ns	
LVCMOS12, Slow, 12 mA	0.98	1.16	2.25	2.45	2.25	2.45	ns	
LVCMOS12, Fast, 2 mA	0.98	1.16	3.60	3.80	3.60	3.80	ns	
LVCMOS12, Fast, 4 mA	0.98	1.16	2.49	2.69	2.49	2.69	ns	
LVCMOS12, Fast, 6 mA	0.98	1.16	1.94	2.14	1.94	2.14	ns	
LVCMOS12, Fast, 8 mA	0.98	1.16	1.82	2.02	1.82	2.02	ns	
LVCMOS12, Fast, 12 mA	0.98	1.16	1.80	2.00	1.80	2.00	ns	
LVCMOS12_JEDEC, QUIETIO, 2 mA	1.57	1.75	6.53	6.73	6.53	6.73	ns	
LVCMOS12_JEDEC, QUIETIO, 4 mA	1.57	1.75	5.12	5.32	5.12	5.32	ns	
LVCMOS12_JEDEC, QUIETIO, 6 mA	1.57	1.75	4.81	5.01	4.81	5.01	ns	
LVCMOS12_JEDEC, QUIETIO, 8 mA	1.57	1.75	4.44	4.64	4.44	4.64	ns	
LVCMOS12_JEDEC, QUIETIO, 12 mA	1.57	1.75	4.20	4.40	4.20	4.40	ns	
LVCMOS12_JEDEC, Slow, 2 mA	1.57	1.75	5.14	5.34	5.14	5.34	ns	
LVCMOS12_JEDEC, Slow, 4 mA	1.57	1.75	2.99	3.19	2.99	3.19	ns	
LVCMOS12_JEDEC, Slow, 6 mA	1.57	1.75	2.90	3.10	2.90	3.10	ns	
LVCMOS12_JEDEC, Slow, 8 mA	1.57	1.75	2.50	2.70	2.50	2.70	ns	
LVCMOS12_JEDEC, Slow, 12 mA	1.57	1.75	2.26	2.46	2.26	2.46	ns	
LVCMOS12_JEDEC, Fast, 2 mA	1.57	1.75	3.60	3.80	3.60	3.80	ns	
LVCMOS12_JEDEC, Fast, 4 mA	1.57	1.75	2.49	2.69	2.49	2.69	ns	
LVCMOS12_JEDEC, Fast, 6 mA	1.57	1.75	1.94	2.14	1.94	2.14	ns	
LVCMOS12_JEDEC, Fast, 8 mA	1.57	1.75	1.83	2.03	1.83	2.03	ns	
LVCMOS12_JEDEC, Fast, 12 mA	1.57	1.75	1.80	2.00	1.80	2.00	ns	

**Notes:**

1. The Spartan-6Q FPGA -1L values are listed in Table 28.

Table 30 summarizes the value of  $T_{IOTPHZ}$ .  $T_{IOTPHZ}$  is described as the delay from the T pin to the IOB pad through the output buffer of an IOB pad, when 3-state is enabled (i.e., a high impedance state). These delays are measured using LVCMOS25, Fast, 12 mA.

Table 30: IOB 3-state ON Output Switching Characteristics ( $T_{IOTPHZ}$ )

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
$T_{IOTPHZ}$	T input to Pad high-impedance	1.39	1.59	1.59	1.91	ns

## I/O Standard Measurement Methodology

### Input Delay Measurements

**Table 31** shows the test setup parameters used for measuring input delay.

**Table 31: Input Delay Measurement Methodology**

Description	I/O Standard Attribute	$V_L^{(1)}$	$V_H^{(1)}$	$V_{MEAS}^{(3)(4)}$	$V_{REF}^{(2)(4)}$
LVTTL (Low-Voltage Transistor-Transistor Logic)	LVTTL	0	3.0	1.4	–
LVCMOS (Low-Voltage CMOS), 3.3V	LVCMOS33	0	3.3	1.65	–
LVCMOS, 2.5V	LVCMOS25	0	2.5	1.25	–
LVCMOS, 1.8V	LVCMOS18	0	1.8	0.9	–
LVCMOS, 1.5V	LVCMOS15	0	1.5	0.75	–
LVCMOS, 1.2V	LVCMOS12	0	1.2	0.6	–
PCI (Peripheral Component Interface), 33 MHz and 66 MHz, 3.3V	PCI33_3, PCI66_3	Per PCI Specification			–
HSTL (High-Speed Transceiver Logic), Class I & II	HSTL_I, HSTL_II	$V_{REF} - 0.5$	$V_{REF} + 0.5$	$V_{REF}$	0.75
HSTL, Class III	HSTL_III	$V_{REF} - 0.5$	$V_{REF} + 0.5$	$V_{REF}$	0.90
HSTL, Class I & II, 1.8V	HSTL_I_18, HSTL_II_18	$V_{REF} - 0.5$	$V_{REF} + 0.5$	$V_{REF}$	0.90
HSTL, Class III 1.8V	HSTL_III_18	$V_{REF} - 0.5$	$V_{REF} + 0.5$	$V_{REF}$	1.1
SSTL (Stub Terminated Transceiver Logic), Class I & II, 3.3V	SSTL3_I, SSTL3_II	$V_{REF} - 0.75$	$V_{REF} + 0.75$	$V_{REF}$	1.5
SSTL, Class I & II, 2.5V	SSTL2_I, SSTL2_II	$V_{REF} - 0.75$	$V_{REF} + 0.75$	$V_{REF}$	1.25
SSTL, Class I & II, 1.8V	SSTL18_I, SSTL18_II	$V_{REF} - 0.5$	$V_{REF} + 0.5$	$V_{REF}$	0.90
SSTL, Class II, 1.5V	SSTL15_II	$V_{REF} - 0.2$	$V_{REF} + 0.2$	$V_{REF}$	0.75
LVDS (Low-Voltage Differential Signaling), 2.5V & 3.3V	LVDS_25, LVDS_33	1.25 – 0.125	1.25 + 0.125	0 <sup>(5)</sup>	–
LVPECL (Low-Voltage Positive Emitter-Coupled Logic), 2.5V & 3.3V	LVPECL_25, LVPECL_33	1.2 – 0.3	1.2 + 0.3	0 <sup>(5)</sup>	–
BLVDS (Bus LVDS), 2.5V	BLVDS_25	1.3 – 0.125	1.3 + 0.125	0 <sup>(5)</sup>	–
Mini-LVDS, 2.5V & 3.3V	MINI_LVDS_25, MINI_LVDS_33	1.2 – 0.125	1.2 + 0.125	0 <sup>(5)</sup>	–
RSDS (Reduced Swing Differential Signaling), 2.5V & 3.3V	RSDS_25, RSDS_33	1.2 – 0.1	1.2 + 0.1	0 <sup>(5)</sup>	–
TMDS (Transition Minimized Differential Signaling), 3.3V	TMDS_33	3.0 – 0.1	3.0 + 0.1	0 <sup>(5)</sup>	–
PPDS (Point-to-Point Differential Signaling), 2.5V & 3.3V	PPDS_25, PPDS_33	1.25 – 0.1	1.25 + 0.1	0 <sup>(5)</sup>	–

**Notes:**

1. Input waveform switches between  $V_L$  and  $V_H$ .
2. Measurements are made at typical, minimum, and maximum  $V_{REF}$  values. Reported delays reflect worst case of these measurements.  $V_{REF}$  values listed are typical.
3. Input voltage level from which measurement starts.
4. This is an input voltage reference that bears no relation to the  $V_{REF}$  /  $V_{MEAS}$  parameters found in IBIS models and/or noted in [Figure 4](#).
5. The value given is the differential input voltage.

Table 32: Output Delay Measurement Methodology (Cont'd)

Description	I/O Standard Attribute	R <sub>REF</sub> (Ω)	C <sub>REF</sub> <sup>(1)</sup> (pF)	V <sub>MEAS</sub> (V)	V <sub>REF</sub> (V)
SSTL, Class II, 2.5V	SSTL2_II	25	0	V <sub>REF</sub>	1.25
SSTL, Class II, 1.5V	SSTL15_II	25	0	V <sub>REF</sub>	0.75
LVDS (Low-Voltage Differential Signaling), 2.5V & 3.3V	LVDS_25, LVDS_33	100	0	0 <sup>(3)</sup>	—
BLVDS (Bus LVDS), 2.5V	BLVDS_25	Note 4	0	0 <sup>(3)</sup>	—
Mini-LVDS, 2.5V & 3.3V	MINI_LVDS_25, MINI_LVDS_33	100	0	0 <sup>(3)</sup>	—
RSDS (Reduced Swing Differential Signaling), 2.5V & 3.3V	RSDS_25, RSDS_33	100	0	0 <sup>(3)</sup>	—
TMDS (Transition Minimized Differential Signaling), 3.3V	TMDS_33	Note 5	0	0 <sup>(3)</sup>	—
PPDS (Point-to-Point Differential Signaling, 2.5V & 3.3V	PPDS_25, PPDS_33	100	0	0 <sup>(3)</sup>	—

**Notes:**

1. C<sub>REF</sub> is the capacitance of the probe, nominally 0 pF.
2. Per PCI specifications.
3. The value given is the differential output voltage.
4. See the *BLVDS Output Termination* section in [UG381, Spartan-6 FPGA SelectIO Resources User Guide](#).
5. See the *TMDS\_33 Termination* section in [UG381, Spartan-6 FPGA SelectIO Resources User Guide](#).

## Simultaneously Switching Outputs

Due to package electrical parasitics, a given package supports a limited number of simultaneous switching outputs (SSOs) when using fast, high-drive outputs. [Table 33](#) and [Table 34](#) provide guidelines for the recommended maximum allowable number of SSOs. These guidelines describe the maximum number of user I/O pins of an output signal standard that should simultaneously switch in the same direction, while maintaining a safe level of switching noise for that particular signal standard. Meeting these guidelines for the stated test conditions ensures that the FPGA operates free from the adverse effects of GND and power bounce.

For each device/package combination, [Table 33](#) provides the number of equivalent V<sub>CCO</sub>/GND pairs per bank. For each output signal standard and drive strength, [Table 34](#) recommends the maximum number of SSOs, switching in the same direction, allowed per V<sub>CCO</sub>/GND pair within an I/O bank. The guidelines are categorized by package style, slew rate, and output drive current. The number of SSOs are also specified by I/O bank. Multiply the appropriate numbers from each table to calculate the maximum number of SSOs allowed within an I/O bank. The guidelines assume that all pins within a bank use the same I/O standard. Exceeding these SSO guidelines can result in increased power or GND bounce, degraded signal integrity, or increased system jitter. For a given I/O standard, if the SSO limit per pair in [Table 34](#) is greater than the maximum I/O per pair in [Table 33](#), then there is no SSO limit for the exclusive use of that I/O standard.

The recommended maximum SSO values assume that the FPGA is soldered on a printed circuit board and that the board uses sound design practices. Due to the additional inductance introduced by the socket, the SSO values do not apply for FPGAs mounted in sockets. The SSO values assume that the V<sub>CCAUX</sub> is powered at 3.3V. Setting V<sub>CCAUX</sub> to 2.5V provides better SSO characteristics. For more detail, see [UG381: Spartan-6 FPGA SelectIO Resources User Guide](#).

Table 34: SSO Limit per V<sub>CCO</sub>/GND Pair (Cont'd)

V <sub>CCO</sub>	I/O Standard	Drive	Slew	SSO Limit per V <sub>CCO</sub> /GND Pair					
				All TQG144, CPG196, CSG225, FT(G)256, and LX devices in CSG324		All CS(G)484, FG(G)484, FG(G)676, FG(G)900, and LXT devices in CSG324			
				Bank 0/2	Bank 1/3	Bank 0/2	Bank 1/3/4/5		
1.5V	LVCMOS15, LVCMOS15_JEDEC	2	Fast	33	40	33	41		
			Slow	57	62	57	56		
			QuietIO	70	67	70	66		
		4	Fast	19	21	19	21		
			Slow	30	30	30	24		
			QuietIO	38	33	38	30		
		6	Fast	14	16	14	16		
			Slow	18	19	18	17		
			QuietIO	27	24	27	21		
		8	Fast	11	13	11	12		
			Slow	16	16	16	14		
			QuietIO	23	20	23	17		
		12	Fast	N/A	5	N/A	4		
			Slow	N/A	8	N/A	5		
			QuietIO	N/A	10	N/A	9		
		16	Fast	N/A	5	N/A	4		
			Slow	N/A	8	N/A	8		
			QuietIO	N/A	10	N/A	9		
HSTL_I				9	10	9	10		
HSTL_II				N/A	5	N/A	6		
HSTL_III				7	9	7	9		
DIFF_HSTL_I				27	30	27	30		
DIFF_HSTL_II				N/A	15	N/A	18		
DIFF_HSTL_III				21	27	21	27		
SSTL_15_II <sup>(3)</sup>				N/A	5	N/A	4		
DIFF_SSTL_15_II <sup>(3)</sup>				N/A	15	N/A	12		

## Input/Output Logic Switching Characteristics

Table 35: ILOGIC2 Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
<b>Setup/Hold</b>						
T <sub>ICE0CK</sub> /T <sub>ICKCE0</sub>	CE0 pin Setup/Hold with respect to CLK	0.56/ -0.30	0.56/ -0.25	0.79/ -0.22	1.21/ -0.52	ns
T <sub>ISRCK</sub> /T <sub>ICKSR</sub>	SR pin Setup/Hold with respect to CLK	0.74/ -0.23	0.74/ -0.22	0.98/ -0.20	1.31/ -0.45	ns
T <sub>IDOCK</sub> /T <sub>IOCKD</sub>	D pin Setup/Hold with respect to CLK without Delay	1.19/ -0.83	1.36/ -0.83	1.73/ -0.83	2.18/ -1.77	ns
T <sub>IDOCKD</sub> /T <sub>IOCKDD</sub>	DDLY pin Setup/Hold with respect to CLK (using IODELAY2)	0.31/ 0.00	0.47/ 0.00	0.54/ 0.00	0.63/ -0.39	ns
<b>Combinatorial</b>						
T <sub>IDI</sub>	D pin to O pin propagation delay, no Delay	0.95	1.28	1.53	2.25	ns
T <sub>IDID</sub>	DDLY pin to O pin propagation delay (using IODELAY2)	0.23	0.39	0.44	0.74	ns
<b>Sequential Delays</b>						
T <sub>IDLO</sub>	D pin to Q pin using flip-flop as a latch without Delay	1.56	1.86	2.39	3.49	ns
T <sub>IDLOD</sub>	DDLY pin to Q1 pin using flip-flop as a latch (using IODELAY2)	0.68	0.97	1.20	1.94	ns
T <sub>ICKQ</sub>	CLK to Q outputs for XC devices	1.03	1.24	1.43	2.11	ns
	CLK to Q outputs for XA and XQ devices	1.38	N/A	1.78	2.11	ns
T <sub>TRQ_ILOGIC2</sub>	SR pin to Q outputs	1.81	1.81	2.50	3.05	ns

Table 36: OLOGIC2 Switching Characteristics

Symbol	Description	Speed Grade				Units
		-3	-3N	-2	-1L	
<b>Setup/Hold</b>						
T <sub>ODCK</sub> /T <sub>OCKD</sub>	D1/D2 pins Setup/Hold with respect to CLK	0.81/ -0.05	0.86/ -0.05	1.18/ 0.00	1.73/ -0.27	ns
T <sub>OOC ECK</sub> /T <sub>OCKOCE</sub>	OCE pin Setup/Hold with respect to CLK	0.75/ -0.10	0.75/ -0.10	1.01/ -0.05	1.66/ -0.23	ns
T <sub>OSRCK</sub> /T <sub>OCKSR</sub>	SR pin Setup/Hold with respect to CLK	0.70/ -0.28	0.79/ -0.28	1.03/ -0.23	1.39/ -0.47	ns
T <sub>OTCK</sub> /T <sub>OCKT</sub>	T1/T2 pins Setup/Hold with respect to CLK	0.24/ -0.08	0.56/ -0.06	0.83/ -0.01	0.99/ -0.19	ns
T <sub>OTCECK</sub> /T <sub>OCKTCE</sub>	TCE pin Setup/Hold with respect to CLK	0.58/ -0.06	0.72/ -0.06	1.18/ -0.01	1.51/ -0.13	ns
<b>Sequential Delays</b>						
T <sub>OCKQ</sub>	CLK to OQ/TQ out for XC devices	0.48	0.51	0.74	0.74	ns
	CLK to OQ/TQ out for XA and XQ devices	0.85	N/A	1.16	0.74	ns
T <sub>TRQ_OLOGIC2</sub>	SR pin to OQ/TQ out	1.81	1.81	2.50	3.05	ns

Table 44: DSP48A1 Switching Characteristics (Cont'd)

Symbol	Description	Pre-adder	Multiplier	Post-adder	Speed Grade				Units
					-3	-3N	-2	-1L	
$T_{DSPDCK\_OPMODE\_PREG}$ / $T_{DSPCKD\_OPMODE\_PREG}$	OPMODE input to P register CLK	Yes	Yes	Yes	6.21/ -0.84	7.27/ -0.84	7.27/ -0.84	10.43/ -0.84	ns
		No	Yes	Yes	1.69/ -0.87	1.98/ -0.87	1.98/ -0.87	3.62/ -0.87	ns
		No	No	Yes	2.09/ -0.22	2.30/ -0.22	2.30/ -0.22	3.79/ -0.22	ns
<b>Clock to Out from Output Register Clock to Output Pin</b>									
$T_{DSPCKO\_P\_PREG}$	CLK (PREG) to P output	N/A	N/A	N/A	1.20	1.34	1.34	1.90	ns
<b>Clock to Out from Pipeline Register Clock to Output Pins</b>									
$T_{DSPCKO\_P\_MREG}$	CLK (MREG) to P output	N/A	N/A	Yes	3.38	3.95	3.95	5.83	ns
<b>Clock to Out from Input Register Clock to Output Pins</b>									
$T_{DSPCKO\_P\_A1REG}$	CLK (A1REG) to P output	N/A	Yes	Yes	5.02	5.87	5.87	9.65	ns
$T_{DSPCKO\_P\_B1REG}$	CLK (B1REG) to P output	N/A	Yes	Yes	5.02	5.87	5.87	9.63	ns
$T_{DSPCKO\_P\_CREG}$	CLK (CREG) to P output	N/A	N/A	Yes	3.12	3.64	3.64	5.24	ns
$T_{DSPCKO\_P\_DREG}$	CLK (DREG) to P output	Yes	Yes	Yes	6.77	7.92	7.92	12.53	ns
<b>Combinatorial Delays from Input Pins to Output Pins</b>									
$T_{DSPDO\_A\_P}$	A input to P output	N/A	No	Yes	2.85	3.33	3.33	4.73	ns
		N/A	Yes	No <sup>(2)</sup>	3.35	3.93	3.93	6.74	ns
		N/A	Yes	Yes	4.56	5.22	5.22	8.94	ns
$T_{DSPDO\_B\_P}$	B input to P output	Yes	No	No <sup>(2)</sup>	3.22	3.76	3.76	5.55	ns
		Yes	Yes	No <sup>(2)</sup>	6.01	6.54	6.54	9.76	ns
		Yes	Yes	Yes	6.27	7.34	7.34	11.96	ns
$T_{DSPDO\_C\_P}$	C input to P output	N/A	N/A	Yes	2.69	3.15	3.15	4.68	ns
$T_{DSPDO\_D\_P}$	D input to P output	Yes	Yes	Yes	6.31	7.38	7.38	11.81	ns
$T_{DSPDO\_OPMODE\_P}$	OPMODE input to P output	Yes	Yes	Yes	6.43	7.52	7.52	11.84	ns
		No	Yes	Yes	4.84	5.66	5.66	9.25	ns
		No	No	Yes	3.11	3.49	3.49	5.03	ns
<b>Maximum Frequency</b>									
$F_{MAX}$	All registers used	Yes	Yes	Yes	390	333	333	213	MHz

**Notes:**

1. A Yes signifies that the component is in the path. A No signifies that the component is being bypassed. N/A signifies not applicable because no path exists.
2. Implemented in the post-adder by adding to zero.

Table 54: Switching Characteristics for the Delay-Locked Loop (DLL)<sup>(1)</sup> (Cont'd)

Symbol	Description	Speed Grade								Units	
		-3		-3N		-2		-1L			
		Min	Max	Min	Max	Min	Max	Min	Max		
LOCK_DLL <sup>(3)</sup>	When using the DLL alone: The time from deassertion at the DCM's reset input to the rising transition at its LOCKED output. When the DCM is locked, the CLKIN and CLKFB signals are in phase. CLKIN_FREQ_DLL < 50 MHz.	—	5	—	5	—	5	—	5	ms	
	When using the DLL alone: The time from deassertion at the DCM's reset input to the rising transition at its LOCKED output. When the DCM is locked, the CLKIN and CLKFB signals are in phase. CLKIN_FREQ_DLL > 50 MHz.	—	0.60	—	0.60	—	0.60	—	0.60	ms	
<b>Delay Lines</b>											
DCM_DELAY_STEP <sup>(5)</sup>	Finest delay resolution, averaged over all steps.	10	40	10	40	10	40	10	40	ps	

**Notes:**

- The values in this table are based on the operating conditions described in Table 2 and Table 53.
- Indicates the maximum amount of output jitter that the DCM adds to the jitter on the CLKIN input.
- For optimal jitter tolerance and faster LOCK time, use the CLKIN\_PERIOD attribute.
- Some jitter and duty-cycle specifications include 1% of input clock period or 0.01 UI. For example, this data sheet specifies a maximum jitter of  $\pm(1\% \text{ of CLKIN period} + 150 \text{ ps})$ . Assuming that the CLKIN frequency is 100 MHz, the equivalent CLKIN period is 10 ns. Since 1% of 10 ns is 0.1 ns or 100 ps, the maximum jitter is  $\pm(100 \text{ ps} + 150 \text{ ps}) = \pm250 \text{ ps}$ .
- A typical delay step size is 23 ps.
- The timing analysis tools use the CLK\_FEEDBACK = 1X condition for the CLKIN\_CLKFB\_PHASE value (reported as phase error). When using CLK\_FEEDBACK = 2X, add 100 ps to the phase error for the CLKIN\_CLKFB\_PHASE value (as shown in this table).

Table 55: Recommended Operating Conditions for the Digital Frequency Synthesizer (DFS)<sup>(1)</sup>

Symbol	Description	Speed Grade								Units	
		-3		-3N		-2		-1L			
		Min	Max	Min	Max	Min	Max	Min	Max		
<b>Input Frequency Ranges<sup>(2)</sup></b>											
CLKIN_FREQ_FX	Frequency for the CLKIN input. Also described as F <sub>CLKIN</sub> .	0.5	375 <sup>(3)</sup>	0.5	375 <sup>(3)</sup>	0.5	333 <sup>(3)</sup>	0.5	200 <sup>(3)</sup>	MHz	
<b>Input Clock Jitter Tolerance<sup>(4)</sup></b>											
CLKIN_CYC_JITT_FX_LF	Cycle-to-cycle jitter at the CLKIN input, based on CLKFX output frequency: F <sub>CLKFX</sub> < 150 MHz.	—	$\pm 300$	—	$\pm 300$	—	$\pm 300$	—	$\pm 300$	ps	
CLKIN_CYC_JITT_FX_HF	Cycle-to-cycle jitter at the CLKIN input, based on CLKFX output frequency: F <sub>CLKFX</sub> > 150 MHz.	—	$\pm 150$	—	$\pm 150$	—	$\pm 150$	—	$\pm 150$	ps	
CLKIN_PER_JITT_FX	Period jitter at the CLKIN input.	—	$\pm 1$	—	$\pm 1$	—	$\pm 1$	—	$\pm 1$	ns	

**Notes:**

- DFS specifications apply when using either of the DFS outputs (CLKFX or CLKFX180).
- When using both DFS and DLL outputs on the same DCM, follow the more restrictive CLKIN\_FREQ\_DLL specifications in Table 53.
- The CLKIN\_DIVIDE\_BY\_2 attribute increases the effective input frequency range. When set to TRUE, the input clock frequency is divided by two as it enters the DCM. Input clock frequencies for the clock buffer being used can be increased up to the F<sub>MAX</sub> (see Table 48 and Table 49 for BUFG and BUFI02 limits).
- CLKIN input jitter beyond these limits can cause the DCM to lose LOCK.

Table 57: Switching Characteristics for the Digital Frequency Synthesizer DFS (DCM\_CLKGEN)<sup>(1)</sup>

Symbol	Description	Speed Grade								Units	
		-3		-3N		-2		-1L			
		Min	Max	Min	Max	Min	Max	Min	Max		
<b>Output Frequency Ranges (DCM_CLKGEN)</b>											
CLKOUT_FREQ_FX	Frequency for the CLKFX and CLKFX180 outputs	5	375	5	375	5	333	5	200	MHz	
CLKOUT_FREQ_FXDV	Frequency for the CLKFXDV output	0.15625	187.5	0.15625	187.5	0.15625	166.5	0.15625	100	MHz	
<b>Output Clock Jitter<sup>(2)(3)</sup></b>											
CLKOUT_PER_JITT_FX	Period jitter at the CLKFX and CLKFX180 outputs.	Typical = ±[0.2% of CLKFX period + 100]								ps	
CLKOUT_PER_JITT_FXDV	Period jitter at the CLKFXDV output.	Typical = ±[0.2% of CLKFX period + 100]								ps	
CLKFX_FREEZE_VAR	CLKFX period change in free running oscillator mode at the same temperature. FCLKFX > 50 MHz	Maximum = ±3% of CLKFX period								ps	
	CLKFX period change in free running oscillator mode at the same temperature. FCLKFX < 50 MHz	Maximum = ±5% of CLKFX period								ps	
CLKFX_FREEZE_TEMP_SLOPE	CLKFX period will change in free oscillator mode over temperature. Add to CLKFX_FREEZE_VAR to determine total CLKFX period change. Percentage change for CLKFX period over 1°C.	Maximum = 0.1								%/°C	
<b>Duty Cycle<sup>(4)(5)</sup></b>											
CLKOUT_DUTY_CYCLE_FX	Duty cycle precision for the CLKFX and CLKFX180 outputs, including the BUFGMUX and clock tree duty-cycle distortion	Maximum = ±[1% of CLKFX period + 350]								ps	
CLKOUT_DUTY_CYCLE_FXDV	Duty cycle precision for the CLKFXDV outputs, including the BUFGMUX and clock tree duty-cycle distortion	Maximum = ±[1% of CLKFX period + 350]								ps	
<b>Lock Time</b>											
LOCK_FX <sup>(2)</sup>	The time from deassertion at the DCM's Reset input to the rising transition at its LOCKED output. The DFS asserts LOCKED when the CLKFX, CLKFX180, and CLKFXDV signals are valid. Lock time requires CLKFX_DIVIDE < $F_{IN}/(0.50 \text{ MHz})$ when: $F_{CLKIN} < 50 \text{ MHz}$	–	50	–	50	–	50	–	50	ms	
	when: $F_{CLKIN} > 50 \text{ MHz}$	–	5	–	5	–	5	–	5	ms	

Table 57: Switching Characteristics for the Digital Frequency Synthesizer DFS (DCM\_CLKGEN)<sup>(1)</sup> (Cont'd)

Symbol	Description	Speed Grade								Units	
		-3		-3N		-2		-1L			
		Min	Max	Min	Max	Min	Max	Min	Max		
<b>Spread Spectrum</b>											
F_CLKIN_FIXED_SPREAD_SPECTRUM	Frequency of the CLKIN input for fixed spread spectrum (SPREAD_SPECTRUM = CENTER_LOW_SPREAD / CENTER_HIGH_SPREAD)	30	200	30	200	30	200	30	200	MHz	
T_CENTER_LOW_SPREAD <sup>(6)</sup>	Spread at the CLKFX output for fixed spread spectrum (SPREAD_SPECTRUM = CENTER_LOW_SPREAD)	Typical = $\frac{100}{\text{CLKFX\_DIVIDE}}$ Maximum = 250								ps	
T_CENTER_HIGH_SPREAD <sup>(6)</sup>	Spread at the CLKFX output for fixed spread spectrum (SPREAD_SPECTRUM = CENTER_HIGH_SPREAD)	Typical = $\frac{240}{\text{CLKFX\_DIVIDE}}$ Maximum = 400								ps	
F_MOD_FIXED_SPREAD_SPECTRUM <sup>(6)</sup>	Average modulation frequency when using fixed spread spectrum (SPREAD_SPECTRUM = CENTER_LOW_SPREAD / CENTER_HIGH_SPREAD)	Typical = $F_{IN}/1024$								MHz	

**Notes:**

- The values in this table are based on the operating conditions described in Table 2 and Table 55.
- For optimal jitter tolerance and a faster LOCK time, use the CLKIN\_PERIOD attribute.
- Output jitter is characterized with no input jitter. Output jitter strongly depends on the environment, including the number of SSOs, the output drive strength, CLB utilization, CLB switching activities, switching frequency, power supply, and PCB design. The actual maximum output jitter depends on the system application.
- The CLKFX, CLKFXDV, and CLKFX180 outputs have a duty cycle of approximately 50%.
- Some duty-cycle and alignment specifications include a percentage of the CLKFX output period. For example, this data sheet specifies a maximum CLKFX jitter of  $\pm(1\% \text{ of CLKFX period} + 200 \text{ ps})$ . Assuming that the CLKFX output frequency is 100 MHz, the equivalent CLKFX period is 10 ns, and 1% of 10 ns is 0.1 ns or 100 ps. Accordingly, the maximum jitter is  $\pm(100 \text{ ps} + 200 \text{ ps}) = \pm300 \text{ ps}$ .
- When using CENTER\_LOW\_SPREAD, CENTER\_HIGH\_SPREAD, the valid values for CLKFX\_MULTIPLY are limited to 2 through 32, and the valid values for CLKFX\_DIVIDE are limited to 1 through 4.

Table 58: Recommended Operating Conditions for the Phase-Shift Clock in Variable Phase Mode (DCM\_SP) or Dynamic Frequency Synthesis (DCM\_CLKGEN)

Symbol	Description	Speed Grade								Units	
		-3		-3N		-2		-1L			
		Min	Max	Min	Max	Min	Max	Min	Max		
<b>Operating Frequency Ranges</b>											
PSCLK_FREQ	Frequency for the PSCLK (DCM_SP) or PROGCLK (DCM_CLKGEN) input.	1	167	1	167	1	167	1	100	MHz	
<b>Input Pulse Requirements</b>											
PSCLK_PULSE	PSCLK (DCM_SP) or PROGCLK (DCM_CLKGEN) pulse width as a percentage of the clock period.	40	60	40	60	40	60	40	60	%	

## Spartan-6 Device Pin-to-Pin Output Parameter Guidelines

All devices are 100% functionally tested. The representative values for typical pin locations and normal clock loading are listed in [Table 63](#) through [Table 69](#). Values are expressed in nanoseconds unless otherwise noted.

**Table 63: Global Clock Input to Output Delay Without DCM or PLL**

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
LVCMOS25 Global Clock Input to Output Delay using Output Flip-Flop, 12mA, Fast Slew Rate, <i>without</i> DCM or PLL							
TICKOF	Global Clock and OUTFF <i>without</i> DCM or PLL	XC6SLX4	6.12	N/A	7.68	9.41	ns
		XC6SLX9	6.12	6.51	7.68	9.41	ns
		XC6SLX16	5.98	6.42	7.48	9.10	ns
		XC6SLX25	6.20	6.69	7.84	9.44	ns
		XC6SLX25T	6.20	6.69	7.84	N/A	ns
		XC6SLX45	6.37	6.88	8.10	9.61	ns
		XC6SLX45T	6.37	6.88	8.10	N/A	ns
		XC6SLX75	6.39	6.99	8.16	10.18	ns
		XC6SLX75T	6.39	6.99	8.16	N/A	ns
		XC6SLX100	6.59	7.18	8.41	10.31	ns
		XC6SLX100T	6.59	7.18	8.41	N/A	ns
		XC6SLX150	6.98	7.68	8.80	10.62	ns
		XC6SLX150T	6.98	7.68	8.80	N/A	ns
		XA6SLX4	6.44	N/A	7.68	N/A	ns
		XA6SLX9	6.44	N/A	7.68	N/A	ns
		XA6SLX16	6.30	N/A	7.48	N/A	ns
		XA6SLX25	6.52	N/A	7.84	N/A	ns
		XA6SLX25T	6.52	N/A	7.84	N/A	ns
		XA6SLX45	6.69	N/A	8.12	N/A	ns
		XA6SLX45T	6.69	N/A	8.12	N/A	ns
		XA6SLX75	6.89	N/A	8.16	N/A	ns
		XA6SLX75T	6.89	N/A	8.16	N/A	ns
		XA6SLX100	N/A	N/A	8.36	N/A	ns
		XQ6SLX75	N/A	N/A	8.16	10.18	ns
		XQ6SLX75T	6.89	N/A	8.16	N/A	ns
		XQ6SLX150	N/A	N/A	8.80	10.62	ns
		XQ6SLX150T	7.61	N/A	8.80	N/A	ns

**Notes:**

- Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

Table 65: Global Clock Input to Output Delay With DCM in Source-Synchronous Mode

Symbol	Description	Device	Speed Grade				Units
			-3	-3N	-2	-1L	
LVCMOS25 Global Clock Input to Output Delay using Output Flip-Flop, 12mA, Fast Slew Rate, <i>with</i> DCM in Source-Synchronous Mode.							
T <sub>CLOCKOFDCM_0</sub>	Global Clock and OUTFF <i>with</i> DCM	XC6SLX4	5.03	N/A	7.21	8.05	ns
		XC6SLX9	5.03	6.13	7.21	8.05	ns
		XC6SLX16	5.08	5.51	6.44	7.96	ns
		XC6SLX25	4.81	5.13	5.69	7.94	ns
		XC6SLX25T	4.81	5.13	5.69	N/A	ns
		XC6SLX45	5.26	5.69	6.63	7.92	ns
		XC6SLX45T	5.26	5.69	6.63	N/A	ns
		XC6SLX75	4.77	5.18	5.88	7.95	ns
		XC6SLX75T	4.77	5.18	5.88	N/A	ns
		XC6SLX100	4.72	5.11	5.76	8.59	ns
		XC6SLX100T	4.76	5.11	5.76	N/A	ns
		XC6SLX150	4.90	5.30	5.93	7.93	ns
		XC6SLX150T	4.90	5.30	5.93	N/A	ns
		XA6SLX4	5.35	N/A	7.21	N/A	ns
		XA6SLX9	5.35	N/A	7.21	N/A	ns
		XA6SLX16	5.42	N/A	6.44	N/A	ns
		XA6SLX25	5.13	N/A	5.69	N/A	ns
		XA6SLX25T	5.13	N/A	5.79	N/A	ns
		XA6SLX45	5.58	N/A	6.63	N/A	ns
		XA6SLX45T	5.58	N/A	6.63	N/A	ns
		XA6SLX75	5.09	N/A	5.87	N/A	ns
		XA6SLX75T	5.09	N/A	5.87	N/A	ns
		XA6SLX100	N/A	N/A	6.44	N/A	ns
		XQ6SLX75	N/A	N/A	5.87	7.95	ns
		XQ6SLX75T	5.09	N/A	5.87	N/A	ns
		XQ6SLX150	N/A	N/A	6.06	7.93	ns
		XQ6SLX150T	5.50	N/A	6.06	N/A	ns

**Notes:**

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. DCM output jitter is already included in the timing calculation.

## Source-Synchronous Switching Characteristics

The parameters in this section provide the necessary values for calculating timing budgets for Spartan-6 FPGA source-synchronous transmitter and receiver data-valid windows.

**Table 78: Duty Cycle Distortion and Clock-Tree Skew**

Symbol	Description	Device <sup>(1)</sup>	Speed Grade				Units
			-3	-3N	-2	-1L	
$T_{DCD\_CLK}$	Global Clock Tree Duty Cycle Distortion <sup>(2)</sup>	LX4	0.20	N/A	0.20	0.35	ns
		LX9	0.20	0.20	0.20	0.35	ns
		LX16	0.20	0.20	0.20	0.35	ns
		LX25	0.20	0.20	0.20	0.35	ns
		LX25T	0.20	0.20	0.20	N/A	ns
		LX45	0.20	0.20	0.20	0.35	ns
		LX45T	0.20	0.20	0.20	N/A	ns
		LX75	0.20	0.20	0.20	0.35	ns
		LX75T	0.20	0.20	0.20	N/A	ns
		LX100	0.20	0.20	0.20	0.35	ns
		LX100T	0.20	0.20	0.20	N/A	ns
		LX150	0.35	0.35	0.35	0.35	ns
		LX150T	0.35	0.35	0.35	N/A	ns
$T_{CKSKEW}$	Global Clock Tree Skew <sup>(3)</sup>	LX4	0.25	N/A	0.25	0.29	ns
		LX9	0.25	0.25	0.25	0.29	ns
		LX16	0.15	0.15	0.15	0.22	ns
		LX25	0.26	0.26	0.26	0.41	ns
		LX25T	0.26	0.26	0.26	N/A	ns
		LX45	0.20	0.20	0.20	0.28	ns
		LX45T	0.20	0.20	0.20	N/A	ns
		LX75	0.56	0.56	0.56	0.50	ns
		LX75T	0.56	0.56	0.56	N/A	ns
		XC6SLX100 <sup>(4)</sup>	0.22	0.22	0.22	0.21	ns
		XA6SLX100 <sup>(4)</sup>	N/A	N/A	0.43	N/A	ns
		LX100T	0.22	0.22	0.22	N/A	ns
		LX150	0.48	0.48	0.48	0.35	ns
		LX150T	0.48	0.48	0.48	N/A	ns
$T_{DCD\_BUFIO2}$	I/O clock tree duty cycle distortion	LX devices	0.25	0.25	0.25	0.50	ns
		LXT devices	0.25	0.25	0.25	N/A	ns